

FEATURES:

- Typical $t_{sk(o)}$ (Output Skew) < 250ps
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- $V_{cc} = 3.3V \pm 0.3V$, Normal Range
- $V_{cc} = 2.7V$ to $3.6V$, Extended Range
- CMOS power levels (0.4 μ W typ. static)
- All inputs, outputs, and I/O are 5V tolerant
- Available in TSSOP package

DRIVE FEATURES:

- Balanced Output Drivers: $\pm 12mA$
- Low switching noise

APPLICATIONS:

- 5V and 3.3V mixed voltage systems
- Data communication and telecommunication systems

DESCRIPTION:

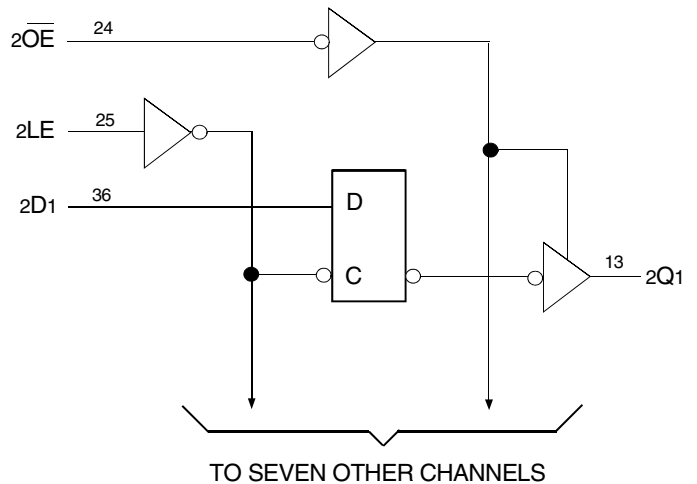
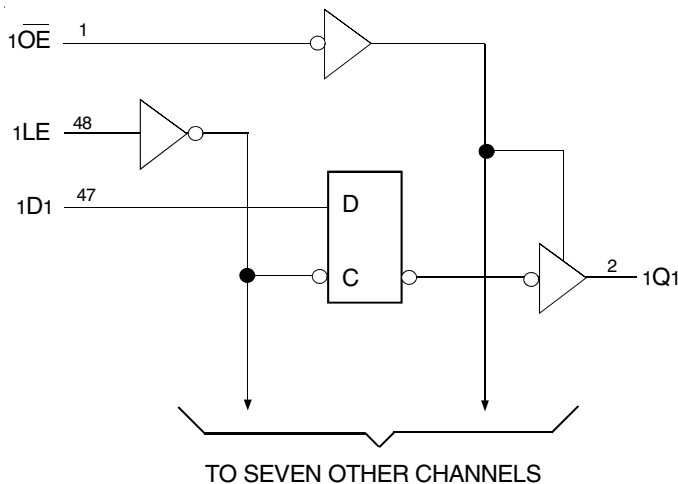
The LVCH162373A 16-bit transparent D-type latch is built using advanced dual metal CMOS technology. This high-speed, low-power latch is ideal for temporary storage of data. The LVCH162373A can be used for implementing memory address latches, I/O ports, and bus drivers. The output enable and latch enable controls are organized to operate each device as two 8-bit latches or one 16-bit latch. Flow-through organization of signal pins simplifies layout. All inputs are designed with hysteresis for improved noise margin.

All pins of the LVCH162373A can be driven from either 3.3V or 5V devices. This feature allows the use of this device as a translator in a mixed 3.3V/5V supply system.

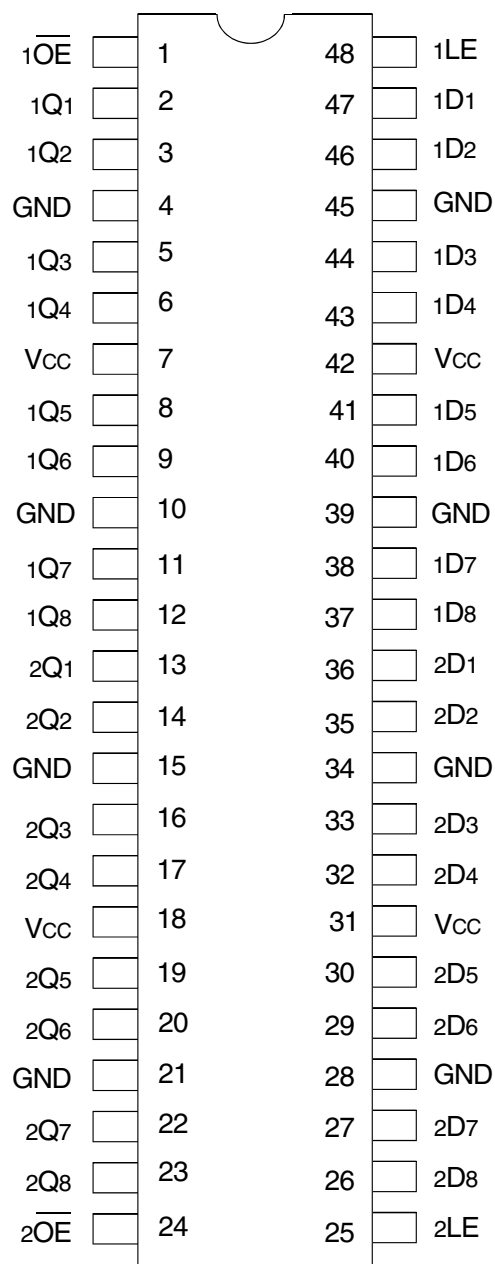
The LVCH162373A has series resistors in the device output structure which will significantly reduce line noise when used with light loads. The driver has been developed to drive $\pm 12mA$ at the designated threshold levels.

The LVCH162373A has “bus-hold” which retains the inputs’ last state whenever the input goes to a high impedance. This prevents floating inputs and eliminates the need for pull-up/down resistors.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION



TSSOP
TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

| Symbol | Description | Max | Unit |
|------------------------------------|---|--------------|------|
| VTERM | Terminal Voltage with Respect to GND | -0.5 to +6.5 | V |
| TSTG | Storage Temperature | -65 to +150 | °C |
| IOUT | DC Output Current | -50 to +50 | mA |
| I _{IK} I _{OK} | Continuous Clamp Current, V _I < 0 or V _O < 0 | -50 | mA |
| I _{CC} I _{SS} | Continuous Current through each V _{CC} or GND | ±100 | mA |

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (T_A = +25°C, F = 1.0MHz)

| Symbol | Parameter ⁽¹⁾ | Conditions | Typ. | Max. | Unit |
|------------------|--------------------------|-----------------------|------|------|------|
| C _{IN} | Input Capacitance | V _{IN} = 0V | 4.5 | 6 | pF |
| C _{OUT} | Output Capacitance | V _{OUT} = 0V | 6.5 | 8 | pF |
| C _{I/O} | I/O Port Capacitance | V _{IN} = 0V | 6.5 | 8 | pF |

NOTE:

- As applicable to the device type.

PIN DESCRIPTION

| Pin Names | Description |
|-----------------|-----------------------------------|
| xD _x | Data Inputs ⁽¹⁾ |
| xLE | Latch Enable Inputs (Active HIGH) |
| xQ _x | 3-State Outputs |
| xOE | Output Enable Inputs (Active LOW) |

NOTE:

- These pins have "Bus-Hold". All other pins are standard inputs, outputs, or I/Os.

FUNCTION TABLE (EACH 8-BIT SECTION)⁽¹⁾

| Inputs | | | Outputs |
|--------|-----|-----------------|------------------|
| xOE | xLE | xD _x | xQ _x |
| L | H | H | H |
| L | H | L | L |
| L | L | X | Q ⁽²⁾ |
| H | X | X | Z |

NOTES:

- H = HIGH Voltage Level
X = Don't Care
L = LOW Voltage Level
Z = High-Impedance
- Output level before the indicated steady-state input conditions were established.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Operating Condition: TA = -40°C to +85°C

| Symbol | Parameter | Test Conditions | | Min. | Typ. ⁽¹⁾ | Max. | Unit |
|--|--|---|---|------|---------------------|------|------|
| V _{IH} | Input HIGH Voltage Level | V _{CC} = 2.3V to 2.7V | | 1.7 | — | — | V |
| | | V _{CC} = 2.7V to 3.6V | | 2 | — | — | |
| V _{IL} | Input LOW Voltage Level | V _{CC} = 2.3V to 2.7V | | — | — | 0.7 | V |
| | | V _{CC} = 2.7V to 3.6V | | — | — | 0.8 | |
| I _{IH} I _{IL} | Input Leakage Current | V _{CC} = 3.6V | V _I = 0 to 5.5V | — | — | ±5 | μA |
| I _{OZH} I _{OZL} | High Impedance Output Current (3-State Output pins) | V _{CC} = 3.6V | V _O = 0 to 5.5V | — | — | ±10 | μA |
| I _{OFF} | Input/Output Power Off Leakage | V _{CC} = 0V, V _{IN} or V _O ≤ 5.5V | | — | — | ±50 | μA |
| V _{IK} | Clamp Diode Voltage | V _{CC} = 2.3V, I _{IN} = -18mA | | — | -0.7 | -1.2 | V |
| V _H | Input Hysteresis | V _{CC} = 3.3V | | — | 100 | — | mV |
| I _{CC1} I _{CC2} I _{CC3} | Quiescent Power Supply Current | V _{CC} = 3.6V | V _{IN} = GND or V _{CC} | — | — | 10 | μA |
| | | | 3.6 ≤ V _{IN} ≤ 5.5V ⁽²⁾ | — | — | 10 | |
| ΔI _{CC} | Quiescent Power Supply Current Variation | One input at V _{CC} - 0.6V, other inputs at V _{CC} or GND | | — | — | 500 | μA |

NOTES:

1. Typical values are at V_{CC} = 3.3V, +25°C ambient.
2. This applies in the disabled state only.

BUS-HOLD CHARACTERISTICS

| Symbol | Parameter ⁽¹⁾ | Test Conditions | | Min. | Typ. ⁽²⁾ | Max. | Unit |
|--|----------------------------------|------------------------|----------------------------|------|---------------------|------|------|
| I _{BHH} I _{BHL} | Bus-Hold Input Sustain Current | V _{CC} = 3V | V _I = 2V | -75 | — | — | μA |
| | | | V _I = 0.8V | 75 | — | — | |
| I _{BHH} I _{BHL} | Bus-Hold Input Sustain Current | V _{CC} = 2.3V | V _I = 1.7V | — | — | — | μA |
| | | | V _I = 0.7V | — | — | — | |
| I _{BHHO} I _{BHLO} | Bus-Hold Input Overdrive Current | V _{CC} = 3.6V | V _I = 0 to 3.6V | — | — | ±500 | μA |

NOTES:

1. Pins with Bus-Hold are identified in the pin description.
2. Typical values are at V_{CC} = 3.3V, +25°C ambient.

OUTPUT DRIVE CHARACTERISTICS

| Symbol | Parameter | Test Conditions ⁽¹⁾ | | Min. | Max. | Unit |
|-------------|---------------------|--------------------------------|--------------|-----------|------|------|
| VOH | Output HIGH Voltage | Vcc = 2.3V to 3.6V | IOH = -0.1mA | Vcc - 0.2 | — | V |
| | | Vcc = 2.3V | IOH = -4mA | 1.9 | — | |
| | | | IOH = -6mA | 1.7 | — | |
| | | Vcc = 2.7V | IOH = -4mA | 2.2 | — | |
| | | | IOH = -8mA | 2 | — | |
| | | Vcc = 3V | IOH = -6mA | 2.4 | — | |
| IOH = -12mA | 2 | | — | | | |
| VOL | Output LOW Voltage | Vcc = 2.3V to 3.6V | IOL = 0.1mA | — | 0.2 | V |
| | | Vcc = 2.3V | IOL = 4mA | — | 0.4 | |
| | | | IOL = 6mA | — | 0.55 | |
| | | Vcc = 2.7V | IOL = 4mA | — | 0.4 | |
| | | | IOL = 8mA | — | 0.6 | |
| | | Vcc = 3V | IOL = 6mA | — | 0.55 | |
| IOL = 12mA | — | | 0.8 | | | |

NOTE:
1. VIH and VIL must be within the min. or max. range shown in the DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE table for the appropriate Vcc range. TA = -40°C to +85°C.

OPERATING CHARACTERISTICS, Vcc = 3.3V ± 0.3V, TA = 25°C

| Symbol | Parameter | Test Conditions | Typical | Unit |
|--------|--|---------------------|---------|------|
| CPD | Power Dissipation Capacitance per Latch Outputs enabled | CL = 0pF, f = 10MHz | — | pF |
| CPD | Power Dissipation Capacitance per Latch Outputs disabled | | — | |

SWITCHING CHARACTERISTICS⁽¹⁾

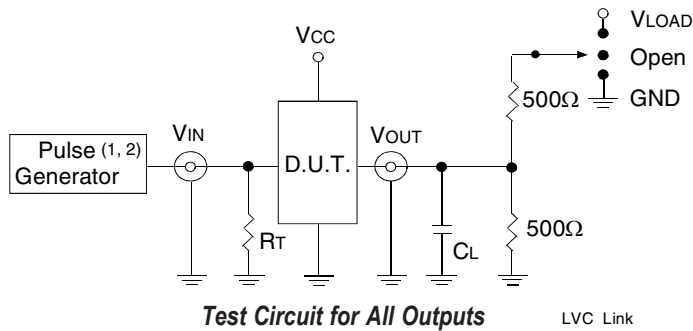
| Symbol | Parameter | Vcc = 2.7V | | Vcc = 3.3V ± 0.3V | | Unit |
|--------|--------------------------------------|------------|------|-------------------|------|------|
| | | Min. | Max. | Min. | Max. | |
| tPLH | Propagation Delay | — | 6 | 1.6 | 5.3 | ns |
| tPHL | xDx to xQx | | | | | |
| tPLH | Propagation Delay | — | 6.4 | 2.1 | 5.7 | ns |
| tPHL | xLE to xQx | | | | | |
| tPZH | Output Enable Time | — | 7.1 | 1.3 | 6.1 | ns |
| tPZL | xOE to xQx | | | | | |
| tPHZ | Output Disable Time | — | 7.7 | 2.5 | 7.3 | ns |
| tPLZ | xOE to xQx | | | | | |
| tsu | Set-up Time HIGH or LOW, xDx to xLE | 2.3 | — | 2.3 | — | ns |
| th | Hold Time HIGH or LOW, xDx after xLE | 1.6 | — | 1.6 | — | ns |
| tw | xLE Pulse Width HIGH | 3.3 | — | 3.3 | — | ns |
| tsk(o) | Output Skew ⁽²⁾ | — | — | — | 500 | ps |

NOTES:
1. See TEST CIRCUITS AND WAVEFORMS. TA = -40°C to +85°C.
2. Skew between any two outputs of the same package and switching in the same direction.

TEST CIRCUITS AND WAVEFORMS

TEST CONDITIONS

| Symbol | V _{CC} ⁽¹⁾ =3.3V±0.3V | V _{CC} ⁽¹⁾ =2.7V | V _{CC} ⁽²⁾ =2.5V±0.2V | Unit |
|-------------------|---|--------------------------------------|---|------|
| V _{LOAD} | 6 | 6 | 2 x V _{CC} | V |
| V _{IH} | 2.7 | 2.7 | V _{CC} | V |
| V _T | 1.5 | 1.5 | V _{CC} / 2 | V |
| V _{LZ} | 300 | 300 | 150 | mV |
| V _{HZ} | 300 | 300 | 150 | mV |
| C _L | 50 | 50 | 30 | pF |



DEFINITIONS:

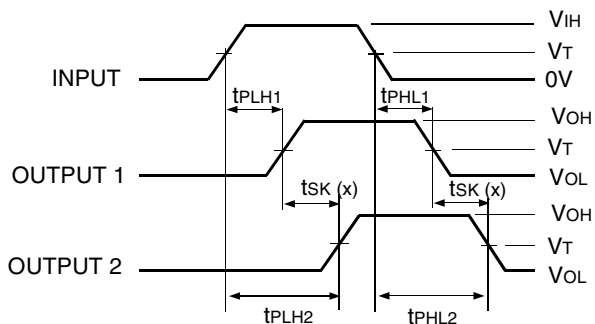
C_L = Load capacitance: includes jig and probe capacitance.
R_T = Termination resistance: should be equal to Z_{OUT} of the Pulse Generator.

NOTES:

1. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_r ≤ 2.5ns; t_f ≤ 2.5ns.
2. Pulse Generator for All Pulses: Rate ≤ 10MHz; t_r ≤ 2ns; t_f ≤ 2ns.

SWITCH POSITION

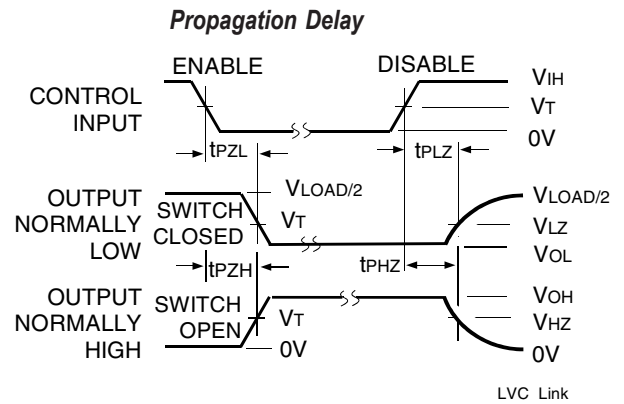
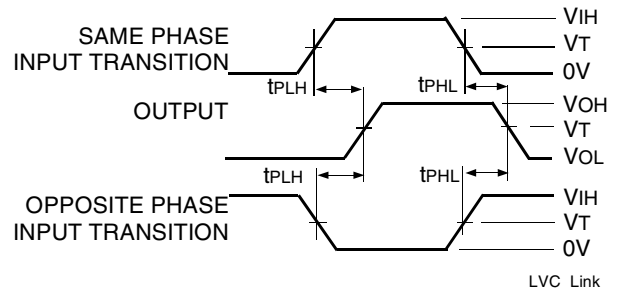
| Test | Switch |
|---|-------------------|
| Open Drain Disable Low Enable Low | V _{LOAD} |
| Disable High Enable High | GND |
| All Other Tests | Open |



$$t_{SK}(x) = |t_{PLH2} - t_{PLH1}| \text{ or } |t_{PHL2} - t_{PHL1}|$$

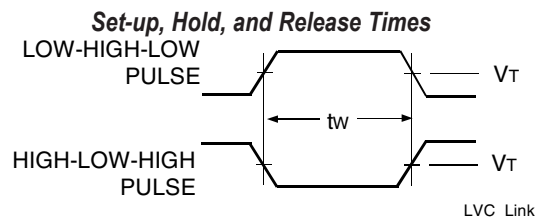
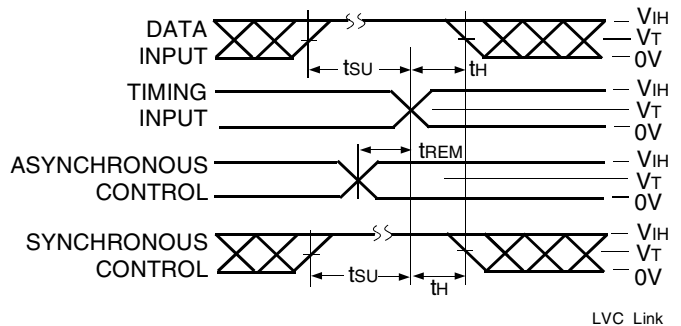
NOTES:

1. For t_{SK}(o) OUTPUT1 and OUTPUT2 are any two outputs.
2. For t_{SK}(b) OUTPUT1 and OUTPUT2 are in the same bank.



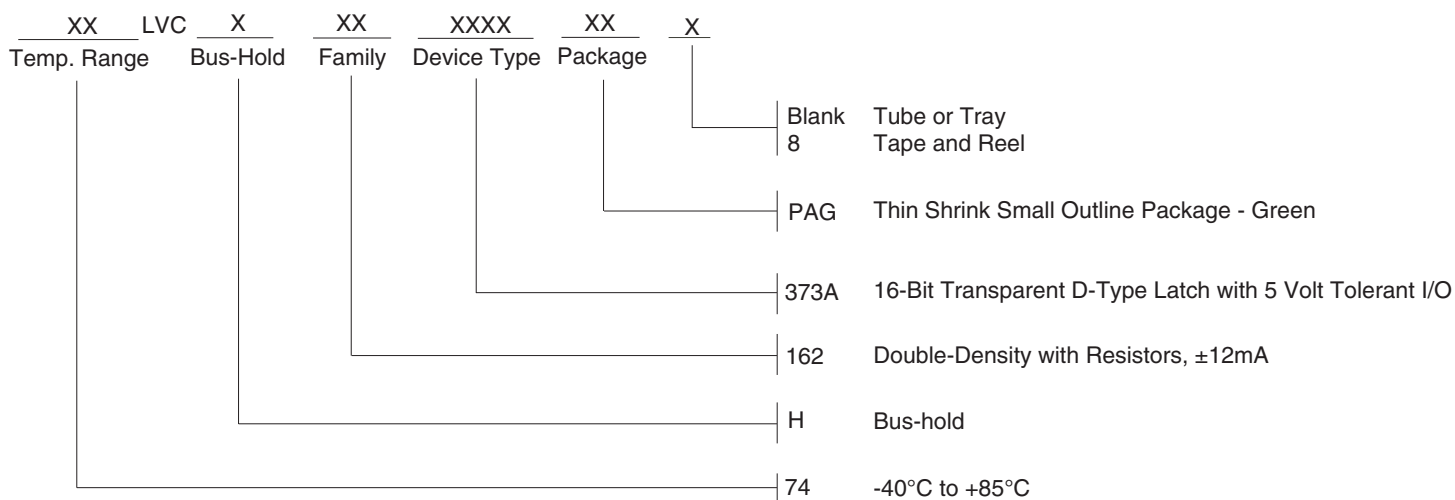
NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.



Pulse Width

ORDERING INFORMATION



DATASHEET DOCUMENT HISTORY

10/06/2015 Pg. 1 ,2, 6 Updated the ordering information by removing non RoHS parts and adding Tape and Reel information.

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